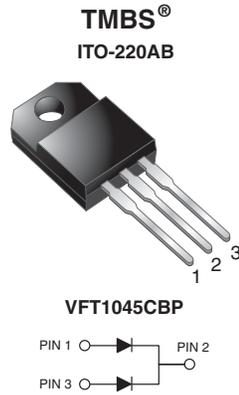


## Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

 Ultra Low  $V_F = 0.34\text{ V}$  at  $I_F = 2.5\text{ A}$ 


### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- $T_J$  200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 5.0 A
$V_{RRM}$	45 V
$I_{FSM}$	100 A
$V_F$ at $I_F = 5.0\text{ A}$	0.41 V
$T_{OP}$ max. (AC mode)	150 °C
$T_J$ max. (DC forward current)	200 °C
Package	ITO-220AB
Diode variation	Dual common cathode

### MECHANICAL DATA

**Case:** ITO-220AB

 Molding compound meets UL 94 V-0 flammability rating  
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VFT1045CBP	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	45	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$ <sup>(1)</sup>	per device	10
		per diode	5.0
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	100	A
Isolation voltage from terminal to heatsink, $t = 1\text{ min}$	$V_{AC}$	1500	V
Operating junction and storage temperature range (AC mode)	$T_{OP}, T_{STG}$	-40 to +150	°C
Junction temperature in DC forward current without reverse bias, $t \leq 1\text{ h}$	$T_J$ <sup>(2)</sup>	$\leq 200$	°C

#### Notes

<sup>(1)</sup> With heatsink

<sup>(2)</sup> Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test



ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.44	-	V
	I <sub>F</sub> = 5.0 A			0.49	0.58	
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.34	-	
	I <sub>F</sub> = 5.0 A			0.41	0.50	
Reverse current per diode	V <sub>R</sub> = 45 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	500	μA
		T <sub>A</sub> = 125 °C		5	15	mA

**Notes**

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VFT1045CBP	UNIT
Typical thermal resistance	per diode	R <sub>θJC</sub>	6.5	°C/W
	per device		5.0	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VFT1045CBP-M3/4W	1.75	4W	50/tube	Tube

**RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)**

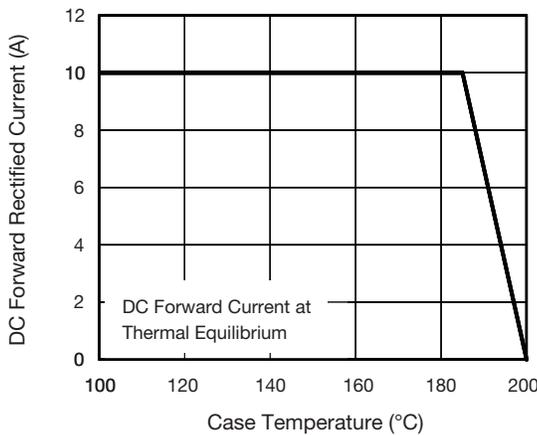


Fig. 1 - Maximum Forward Current Derating Curve

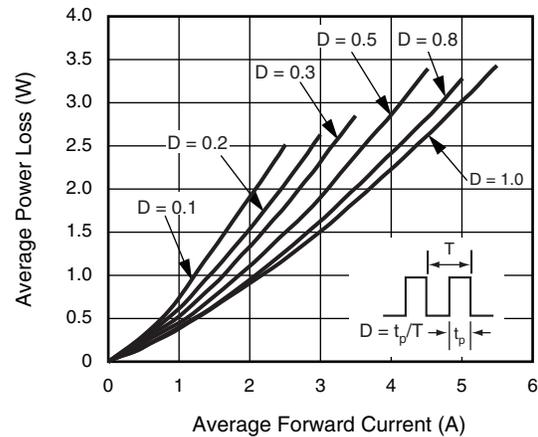


Fig. 2 - Forward Power Loss Characteristics Per Diode

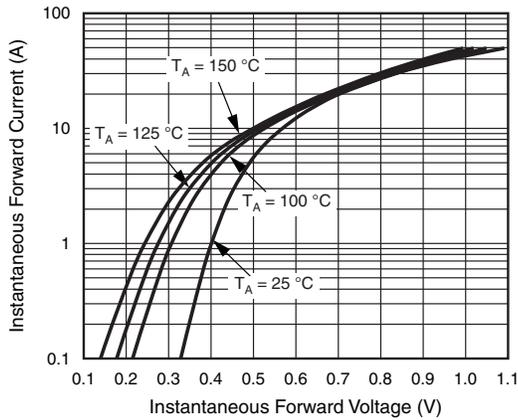


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

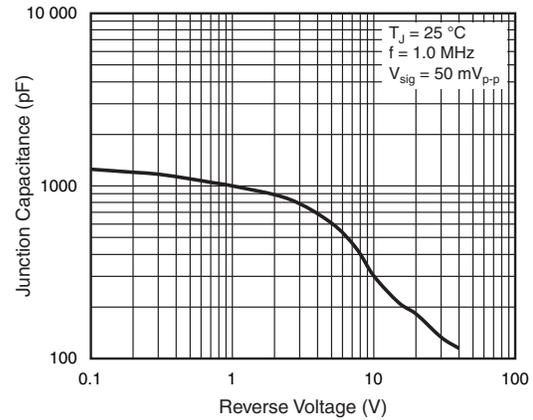


Fig. 5 - Typical Junction Capacitance Per Diode

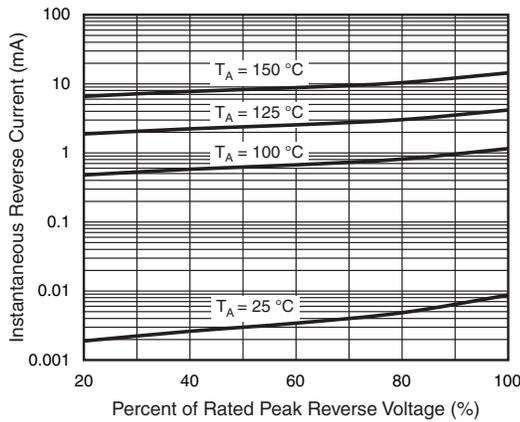


Fig. 4 - Typical Reverse Characteristics Per Diode

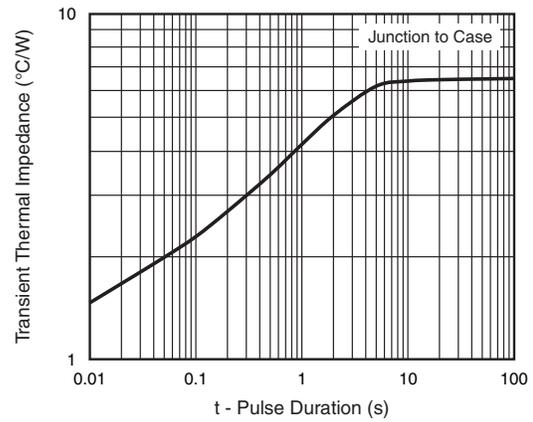
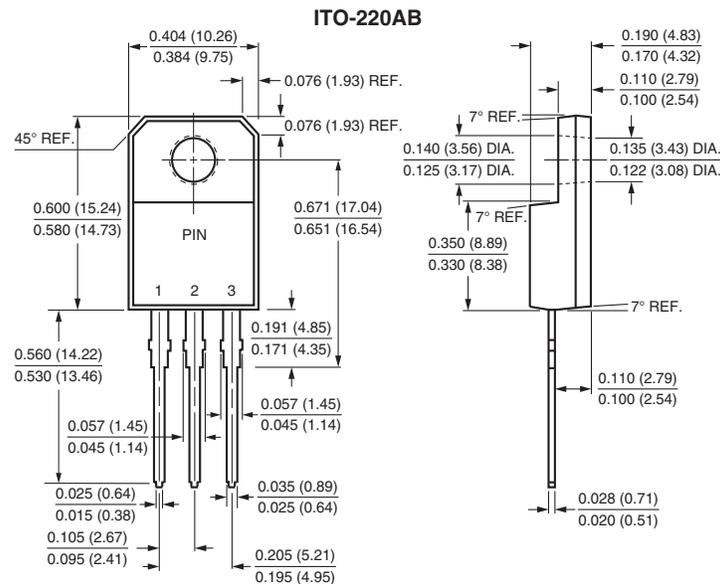


Fig. 6 - Typical Transient Thermal Impedance Per Diode

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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